

2MBI900VXA-120P-50

IGBT Modules

IGBT MODULE (V series) 1200V / 900A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



Maximum Ratings and Characteristics

■ Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions		Maximum ratings	Units	
Collector-Emitter voltage	Vces				V	
Gate-Emitter voltage	VGES			±20	V	
Collector current	lo	Continuous	Tc=25°C	1200		
	Ic		Tc=100°C	900		
	Ic pulse	1ms		1800	Α	
	-lc			900		
	-lc pulse	1ms		1800		
Collector power dissipation	Pc	1 device		5100	W	
Junction temperature	Tj			175		
Operating junction temperature (under swite	ching conditions) T _{jop}			150	°C	
Case temperature	Tc			150		
Storage temperature	Tstg			-40 ~ +150		
Isolation voltage between terminal and	copper base (*1)	AC : 1min	AC : 1min.		VAC	
between thermistor an	nd others (*2)	AC . IIIIII.				
Mounting		M5	M5		N m	
Screw torque (*3) Main Terminals	-	M8	M8 M4			
Sense Terminals		M4				

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable Value: Mounting 3.0 ~ 6.0 Nm (M5) Recommendable Value: Main Terminals 8.0 ~ 10.0 Nm (M8)

Recommendable Value: Sense Terminals 1.8 ~ 2.1 Nm (M4)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

tems	Comple ede	Symbols Conditions		Ch	aracterist	ics	Haita
ems	Symbols			min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	8.0	mA
Gate-Emitter leakage current	Iges	V _{CE} = 0V, V _{GE} = ±20V		-	-	1600	nA
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 900mA		6.0	6.5	7.0	V
Collector-Emitter saturation voltage	V _{CE (sat)}	V _{GE} = 15V I _C = 900A	Tj=25°C	-	1.75	2.20	V
	(terminal)		Tj=125°C	-	2.10	-	
	(*4)		Tj=150°C	-	2.15	-	
	V		Tj=25°C	-	1.65	2.10	
	V _{CE (sat)}		Tj=125°C	-	2.00	-	
	(chip)		Tj=150°C	-	2.05	-	
Input capacitance	Cies	Vce = 10V, Vge = 0V, f = 1N	ЛHz	-	83	-	nF
Turn-on time Turn-off time	ton	V _{cc} = 600V		-	1.00	-	μs
	tr			-	0.40	-	
	tr (i)	⊢lc = 900A -V _{GE} = ±15V	-	0.15	-		
	toff	$R_{G} = 1.6\Omega$		-	1.20	-	
	tf			-	0.15	-	
Forward on voltage	V _F		Tj=25°C	-	1.90	2.35	
	(terminal)		Tj=125°C	-	2.05	-	
	(*4)	$V_{GE} = 0V$	Tj=150°C	-	2.00	-	V
	V _F	I _F = 900A	Tj=25°C	-	1.80	2.25	V
			Tj=125°C	-	1.95	-	
	(chip)		Tj=150°C	-	1.90	-	
Reverse recovery time	trr	I _F = 900A	* *	-	0.20	-	μs
Resistance B value	Б	T=25°C		-	5000	-	Ω
	R	T=100°C		465	495	520	
B value	В	T=25/50°C		3305	3375	3450	K

Note *4: Please refer to page 6, there is definition of on-state voltage at terminal.

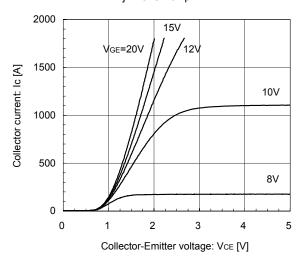
Thermal resistance characteristics

Itama	Symbols	Conditions	Characteristics			Units
Items			min.	typ.	max.	Units
Thormal register as (1 device)	Rth(j-c)	Inverter IGBT	-	-	0.030	°C/W
Thermal resistance (1device)		Inverter FWD	-	-	0.054	
Contact thermal resistance (1device) (*5)	Rth(c-f)	with Thermal Compound		0.00625	-	

■ Characteristics (Representative)

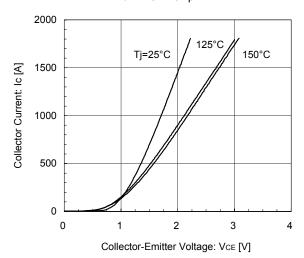
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip



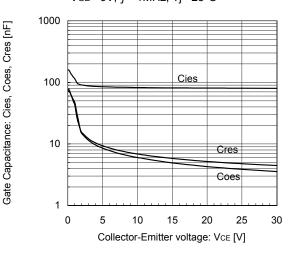
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) VGE= 15V / chip



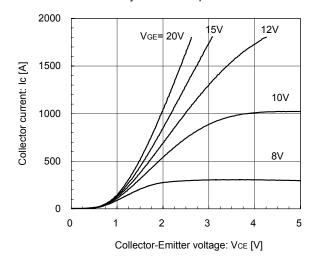
[INVERTER]

Gate Capacitance vs. Collector-Emitter Voltage (typ.) $V_{GE} = 0V, f = 1MHz, Tj = 25^{\circ}C$



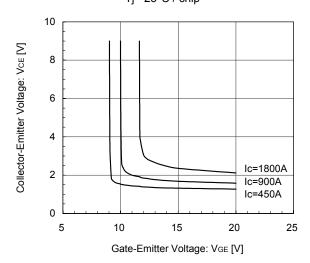
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip



[INVERTER]

Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) $T_j = 25$ °C / chip

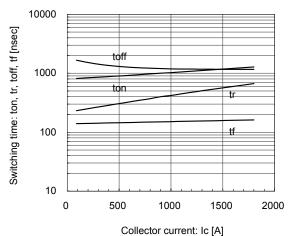


[INVERTER]

Dynamic Gate Charge (typ.) Vcc=600V, Ic=900A, Tj= 25°C

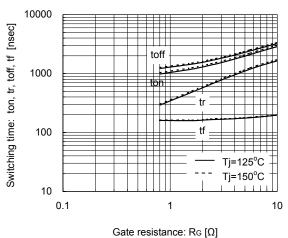
Collector-Emitter voltage: Vce [200V/div] Gate-Emitter voltage: Vce [50//div] Gate-Emitter voltage: Vce [50//div] Gate-Emitter voltage: Qg [6000 9000 Gate charge: Qg [nC]

 $[INVERTER] $$ Switching time vs. Collector current (typ.) $$ Vcc=600V, VgE=\pm15V, Rg=1.6\Omega, Tj=25^{\circ}C$$



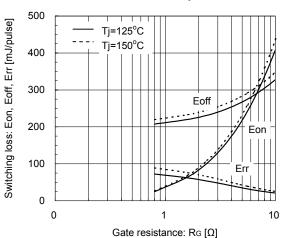
[INVERTER]

Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=900A, VGE=±15V, Tj=125°C, 150°C



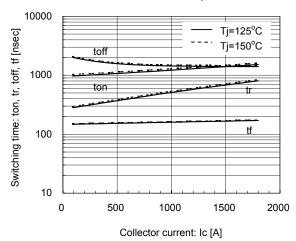
[INVERTER]

Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=900A, $VGE=\pm15V$, $Tj=125^{\circ}C$, $150^{\circ}C$



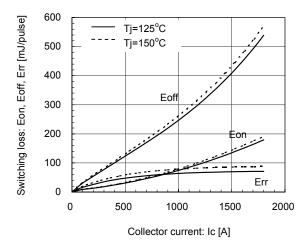
[INVERTER]

Switching time vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg=1.6 Ω , Tj=125°C, 150°C



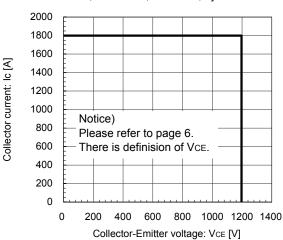
[INVERTER]

Switching loss vs. Collector current (typ.) Vcc=600, VgE= \pm 15V, Rg= 1.6Ω , Tj= 125° C, 150° C



[INVERTER]

Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, RG=1.6 Ω , Tj=150°C



[INVERTER]
Forward Current vs. Forward Voltage (typ.) chip

2000
Tj=25°C
1500
150°C
150°C
2000
150°C
3 3

Reverse Recovery Characteristics (typ.)
Vcc=600V, VGE=±15V, RG=1.6Ω, Tj=25°C

10000

10000

1000

1rr

1rr

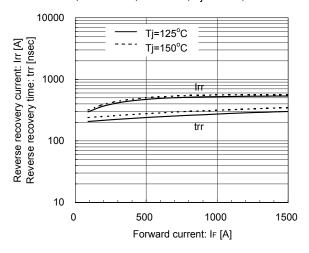
100

0 500 1000 1500

[INVERTER]

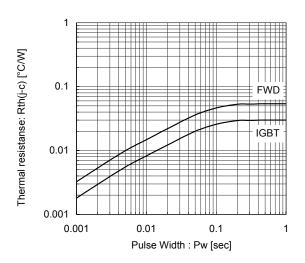
[INVERTER]
Reverse Recovery Characteristics (typ.)
Vcc=600V, VgE=±15V, Rg=1.6Ω, Tj=125°C, 150°C

Forward on voltage: VF [V]



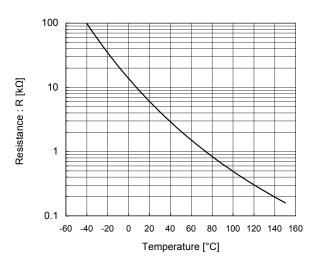
Transient Thermal Resistance (max.)

Forward current: IF [A]

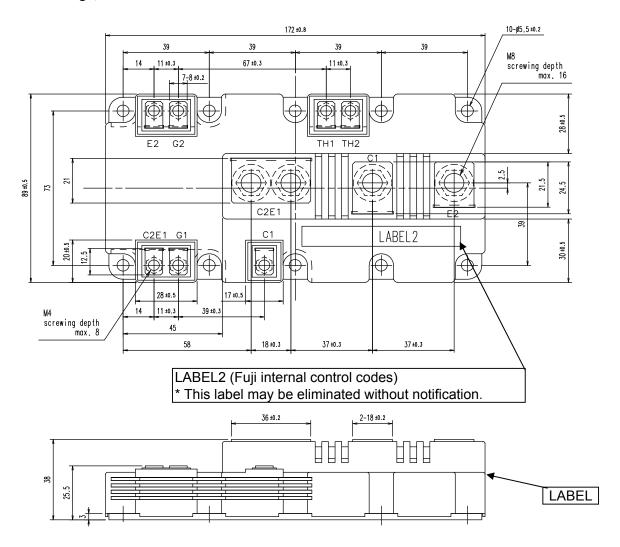


[THERMISTOR]

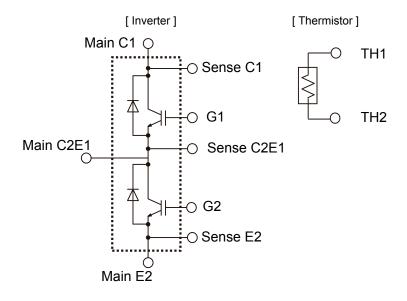
Temperature characteristic (typ.)



■ Outline Drawings, mm

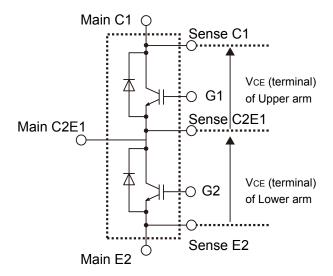


■ Equivalent Circuit Schematic



http://www.fujielectric.com/products/semiconductor/

■ Definition of on-state voltage at terminal and switching characteristics



Fuji defined VcE value of terminal by using Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm.

Switching characteristics of VcE also is defined between Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm .

Please use these terminals whenever measure spike voltage and on-state voltage .

http://www.fujielectric.com/products/semiconductor/

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- · OA equipment
- Communications equipment (terminal devices)
- Measurement equipment

- Machine tools
- Audiovisual equipment Electrical home appliances
- Personal equipment Industrial robots etc.

Trunk communications equipment

· Gas leakage detectors with an auto-shut-off feature

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- Medical equipment
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· Safety devices

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